

## **Constant Current LED Drivers**

# 50V 200mA

## 1ch Source Driver for Automotive

BD8372HFP-M BD8372EFJ-M BD8372UEFJ-M

#### **General Description**

BD8372HFP-M, BD8372EFJ-M and BD8372UEFJ-M are LED source drivers capable of withstanding high input voltage (50V MAX). The constant current output is set by either of two external resistors. It has built-in LED open/short protection, external resistance open/short protection and overvoltage protection that can achieve high reliability. It is possible to control all LEDs together and turn OFF even if LED causes short/open in a certain row when driving two or more LEDs by using multiple ICs.

#### **Features**

- Variable form Constant- Current Source
- H/L Current Setting Switch Control
- LED Open/Short Protection Circuit Integrated
- ISET Open/Short Protection Circuit Integrated
- Overvoltage Mute and Temperature Protection Function Integrated
- Abnormal Output Detection and Output Functions (PBUS)

#### **Applications**

For automotive (Rear lamp, Interior light, etc.).

#### **Key Specifications**

Input Voltage Range: 5.5V to 40V
 Max Output Current: 200mA(MAX)
 Output Current Accuracy: ±8%(Max)
 Operating Temperature Range: -40°C to +125°C

## **Packages**

HRP7 HTSOP-J8 W (Typ) x D (Typ) x H (Max) 9.395mm x 10.540mm x 2.005mm 4.90mm x 6.00mm x 1.00mm





HTSOP-J8

## **Basic Application Circuit**

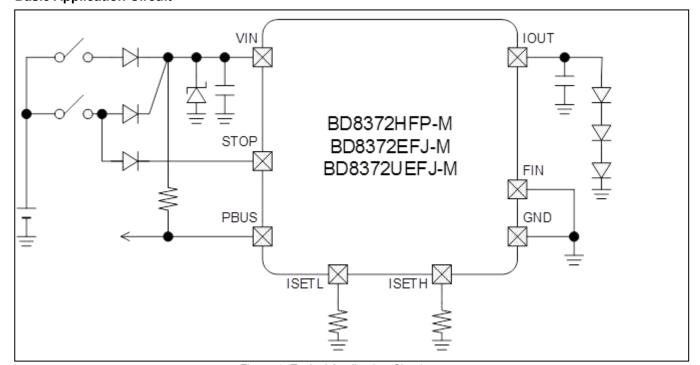


Figure 1. Typical Application Circuit

## **Pin Configurations**

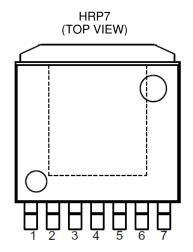


Figure 2. HRP7 Package Pin Configuration

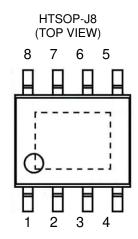


Figure 3. HTSOP-J8 Package Pin Configuration

## **Pin Descriptions**

HRP7

Pin No.	Pin Name	Description
1	STOP	Input terminal for Brake lamp
2	PBUS	Error detection I/O terminal
3	ISETL	Current setting terminal (L mode)
4	GND	GND
5	ISETH	Current setting terminal (H mode)
6	VIN	Power supply input
7	IOUT	Current output terminal

## HTSOP-J8

Pin No.	Pin Name	Description
1	VIN	Power supply input
2	IOUT	Current output terminal
3	GND	GND
4	GND	GND
5	STOP	Input terminal for Brake lamp
6	PBUS	Error detection I/O terminal
7	ISETL	Current setting terminal (L mode)
8	ISETH	Current setting terminal (H mode)

## **Block Diagram**

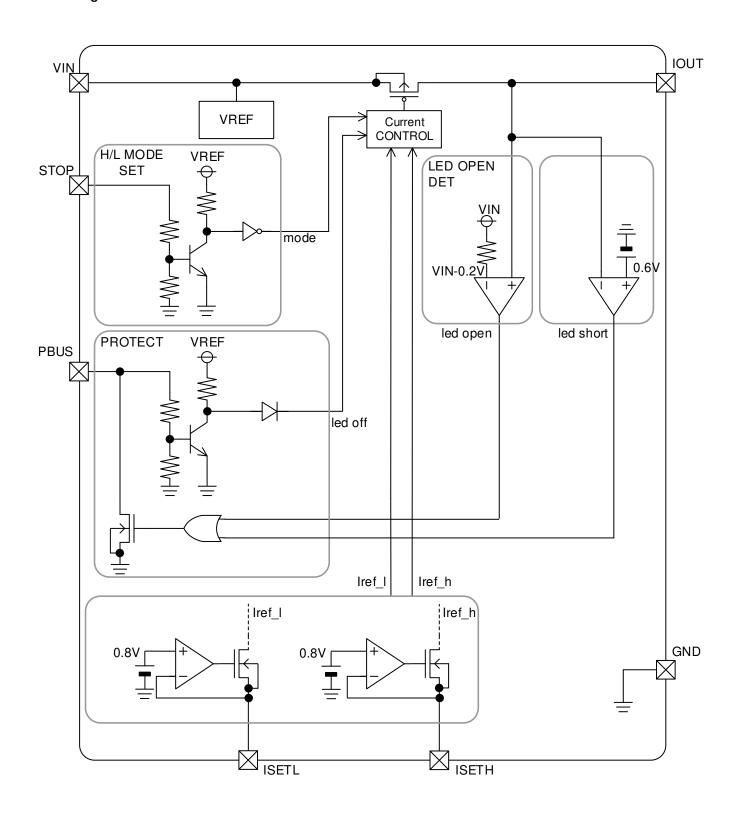


Figure 4. Block Diagram

**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol		Symbol Rating U					
Power Supply Voltage	V <sub>IN</sub>		Vin		Vin		-0.3 to +50	V
STOP, IOUT, PBUS Terminal	VSTOP, VIOUT, VPBUS		VSTOP, VIOUT, VPBUS		VSTOP, VIOUT, VPBUS		-0.3 to V <sub>IN</sub> +0.3	V
ISETH, ISETL Terminal	V	SETH, VISETL	-0.3 to +7	V				
Device Consumentian	Pd	HRP7	2.3 (Note 1)	W				
Power Consumption		HTSOP-J8	1.1 (Note 2)					
Operating Temperature Range		Topr	-40 to +125	°C				
Storage Temperature Range	Tstg		Tstg		-55 to +150	°C		
Junction Temperature	Tjmax		Tjmax		Tjmax		150	°C
IOUT Output Maximum Current		Іюит	200	mA				

<sup>(</sup>Note 1) HRP7

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

## **Recommended Operating Conditions** (Ta=-40°C to +125°C)

(Please set after considering power consumption for the power-supply voltage.)

Parameter	Symbol	Rating			Unit	Conditions
Farameter	Symbol	Min	Тур	Max	Offic	Conditions
Power Supply Voltage	V <sub>IN</sub>	5.5	13	40	V	-
Command Catting Designar	R <sub>ISETH</sub>	10	-	100	kΩ	STOP=H
Current Setting Resistor	RISETL	10	-	100	kΩ	STOP=L
Minimum Capacitor connecting IOUT terminal	Сюит	0.1	-	-	μF	

 $IC\ mounted\ on\ glass\ epoxy\ 2-layer\ board\ area\ 15mmx15mm\ of\ the\ back\ copper\ foil,\ measuring\ 70mmx70mmx1.6mm.$ 

Pd decreased at 18.4mw/°C for temperatures above Ta=25°C. HTSOP-J8

<sup>(</sup>Note 2)

IC mounted on glass epoxy 2-layer board area 15mmx15mm of the back copper foil, measuring 70mmx70mmx1.6mm. Pd decreased at 8.8mW/°C for temperatures above Ta=25°C.

## **Electrical Characteristics**

(Unless otherwise specified, Ta=-40°C to 125°C,  $V_{IN}$ =13V,  $R_{ISETL}$ = $R_{ISETH}$ =40k $\Omega$ ,  $R_{PBUS}$ =10k $\Omega$ )

		Limit			AZZ, TIPBUS – TURZZ)	
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Circuit Current	Ivin	-	2.9	5	mA	
IOUT Output Current H	Іоит_н	48.5	50	51.5	mA	50mA setting (I <sub>SET</sub> =40kΩ) STOP=High, Ta=25°C
1001 Output Guitent 11	1001_н	46	50	54	mA	50mA setting (I <sub>SET</sub> =40kΩ) STOP=High, Ta=-40°C to +125°C
IOLIT Output Output		4.85	5	5.15	mA	5mA setting (I <sub>SET</sub> =40kΩ) STOP=Low, Ta=25°C
IOUT Output Current L	lout_l	4.6	5	5.4	mA	5mA setting (I <sub>SET</sub> =40kΩ) STOP=Low, Ta=-40°C to +125°C
IOUT Drop Voltage H	V <sub>DRH_IOUT</sub>	-	0.7	1.2	٧	200mA setting(I <sub>SET</sub> =10kΩ) STOP=High
IOUT Drop Voltage L	V <sub>DRL_IOUT</sub>	-	0.5	0.7	V	20mA setting(I <sub>SET</sub> =10kΩ) STOP=Low
IOUT OFF Current	I <sub>IOUT_OFF</sub>	-	-	1	μΑ	V <sub>IOUT</sub> =2V, PBUS=L, Ta=25°C
IOUT Current at GND Short	liout_short	-	-	40	μΑ	V <sub>IOUT</sub> =0V
ISET Terminal Voltage	VISET	-	0.8	-	V	At ISETL or ISETH pins
ISET Short Detection Resistor	RISET_SHORT	-	5.1k	7.5k	Ω	At ISETL or ISETH pins
ISET Open Detection Resistor	RISET_OPEN	125k	400k	-	Ω	At ISETL or ISETH pins
IOUT LED OPEN Detection	VIOUT_OPEN	V <sub>IN</sub> -0.3	V <sub>IN</sub> -0.2	V <sub>IN</sub> -0.1	V	
IOUT LED Short Detection	VIOUT_SHORT	0.2	0.6	1.0	V	
STOP Input Voltage H	V <sub>IH_STOP</sub>	4.0	-	V <sub>IN</sub> +0.2	V	
STOP Input Voltage L	V <sub>IL_STOP</sub>	GND	-	1.0	V	
STOP Input Current	I <sub>IN_STOP</sub>	-	40	100	μΑ	V <sub>STOP</sub> =13V
PBUS Input Voltage H	V <sub>IH_PBUS</sub>	4.0	-	V <sub>IN</sub> +0.2	V	
PBUS Input Voltage L	V <sub>IL_PBUS</sub>	GND	-	2.0	V	
PBUS Low Voltage	V <sub>OL_PBUS</sub>	-	-	1.5	V	I <sub>PBUS</sub> =20mA
PBUS Input Current	I <sub>IN_PBUS</sub>	-	38	100	μΑ	V <sub>PBUS</sub> =13V
IN Under Voltage Open Detection Mask Voltage	Vuvlo_iopen	7.5	8.0	8.5	V	
Over Voltage Mute Voltage	VIN_OVPMUTE	16	19	24	V	200mA setting (I <sub>SET</sub> =10kΩ) STOP=High

## **Typical Performance Curves (Reference Data)**

(Unless otherwise specified Ta=25° C, V<sub>IN</sub>=13V)

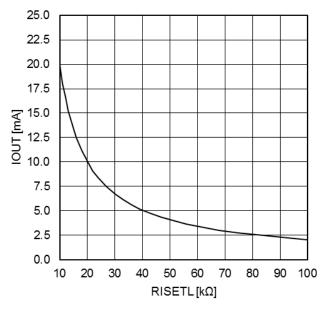
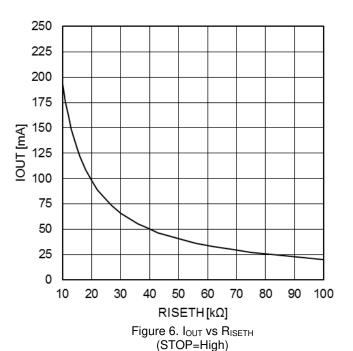


Figure 5. IOUT VS RISETL (STOP=Low)



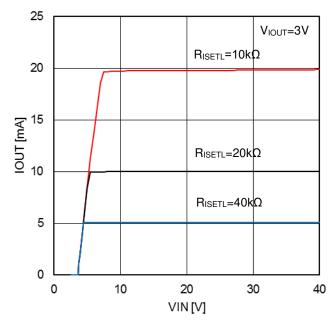


Figure 7.  $I_{OUT}$  vs  $V_{IN}$  (STOP=Low)

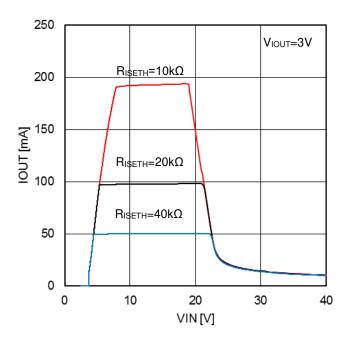


Figure 8. Iout vs V<sub>IN</sub> (STOP=High)

## Typical Performance Curves (Reference Data) - continued

(Unless otherwise specified Ta=25° C, V<sub>IN</sub>=13V)

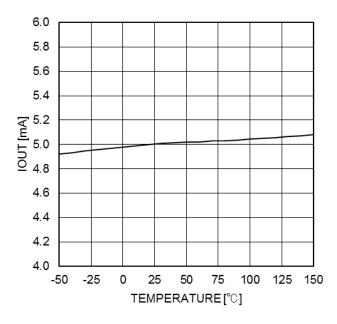
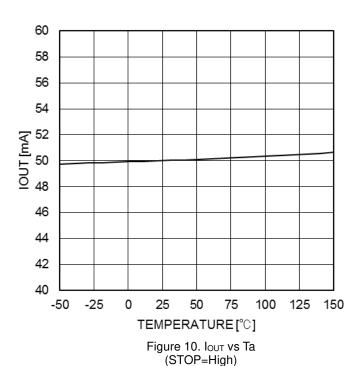


Figure 9. I<sub>OUT</sub> vs Ta (STOP=Low)



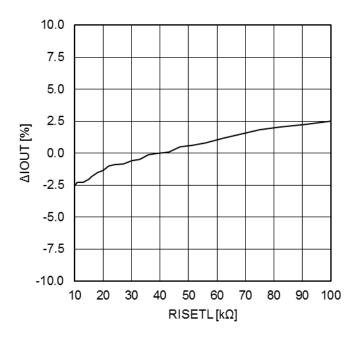


Figure 11.  $\Delta I_{OUT}$  vs  $R_{ISETL}$  (STOP=Low)

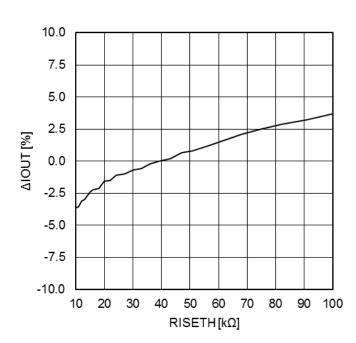
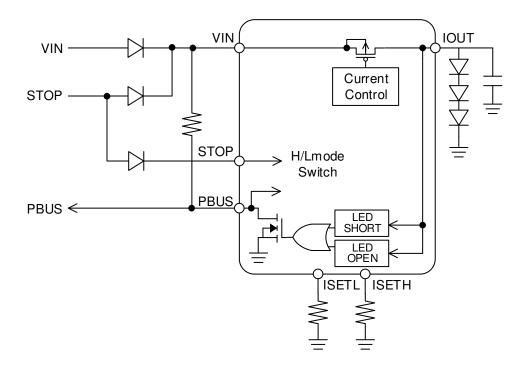


Figure 12. Δl<sub>OUT</sub> vs R<sub>ISETH</sub> (STOP=High)

## **Timing Chart**



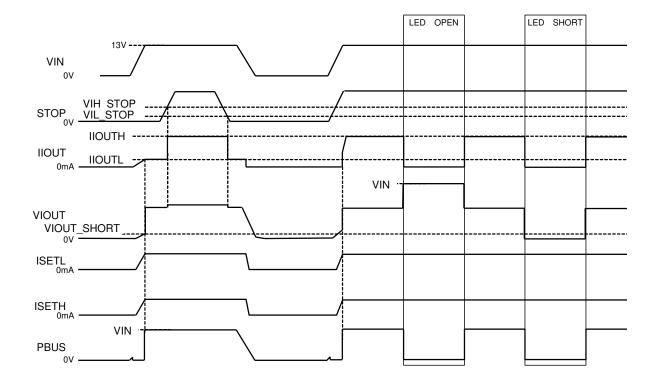


Figure 13. Timing Chart

## **Function Description**

(Unless otherwise specified, Ta=25°C,  $V_{IN}$ =13V,  $R_{ISETL}$ = $R_{ISETH}$ =40k $\Omega$ , the numerical value in the table are TYP values.)

## 1. Table for Operation

STOP	VIOUT	RISETL	Riseth	MODE	Іоит	PBUS
L	2V <v<sub>IOUT <v<sub>IN-0.7V(Max)</v<sub></v<sub>	10kΩ≤R <sub>ISETL</sub> ≤100kΩ	-	L mode normal operation	2mA to 20mA	Hi-Z
Н	2V <v<sub>IOUT <v<sub>IN-1.2V(Max)</v<sub></v<sub>	-	10kΩ≤R <sub>ISETH</sub> ≤100kΩ	H mode normal operation	20mA to 200mA	Hi-Z
L/H	V <sub>IOUT</sub> ≤0.6V(Typ)	-	-	Output short	40μA(Max)	LOW output
L/H	V <sub>IOUT</sub> ≥ V <sub>IN</sub> -0.2V(Typ)	-	-	Output open	1μA(Max)	LOW output
L	-	R <sub>ISETL</sub> <7.5kΩ(Max)	-	I <sub>SETL</sub> short	1μA(Max)	LOW output
L	-	R <sub>ISETL</sub> >125kΩ(Min)	-	I <sub>SETL</sub> open	1μA(Max)	LOW output
Н	-	-	R <sub>ISETH</sub> <7.5kΩ(Max)	I <sub>SETH</sub> short	1μA(Max)	LOW output
Н	-	-	R <sub>ISETH</sub> >125kΩ(Min)	I <sub>SETH</sub> open	1μA(Max)	LOW output
L	2V <v<sub>IOUT <v<sub>IN-0.7V(Max)</v<sub></v<sub>	10kΩ≤R <sub>ISETL</sub> ≤100kΩ	-	PBUS control OFF	1μA(Max)	LOW input
Н	2V <v<sub>IOUT <v<sub>IN-1.2V(Max)</v<sub></v<sub>	-	10kΩ≤R <sub>ISETH</sub> ≤100kΩ	PBUS control OFF	1μA(Max)	LOW input

Protection Mode Operation Voltage( The numerical value are typical )

V <sub>IN</sub>	LED open	LED short	ISET open	ISET short	PBUS	Overvoltage protection
5.5V <v<sub>IN≤8V</v<sub>	×	0	0	0	0	×
8V≤V <sub>IN</sub> ≤19V	0	0	0	0	0	×
19V≤V <sub>IN</sub>	0	0	0	0	0	0

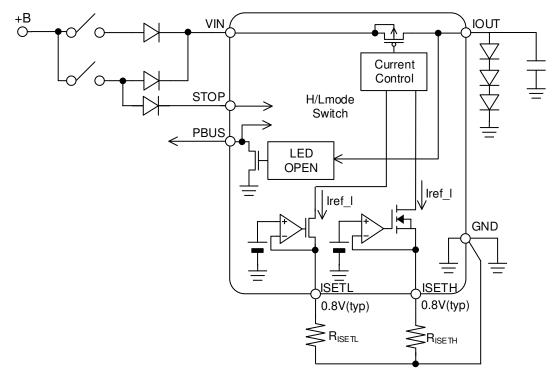
o: Protection mode ON

The LED open function is masked with  $V_{IN} \le 8V$ .

<sup>× :</sup> Protection mode OFF

#### 2. Method of Setting Current

The IC regulates the voltage at ISETL/ISETH to  $V_{ISET}$  (0.8V typ) across the external resistor to set  $I_{OUT}$ . Then  $I_{OUT}$  is set by setting STOP High or Low.



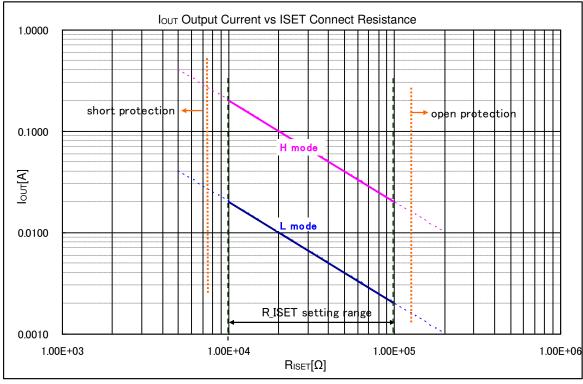


Figure 14. Current setting method

● L mode (STOP=Low)

■ H mode (STOP=High)

$$I_{IOUT} = \frac{0.8V}{R_{ISETL}} \times 250A$$

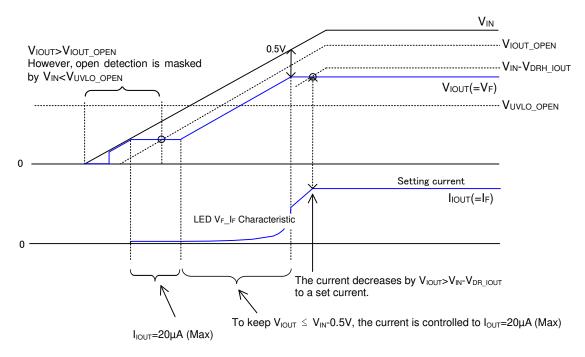
$$I_{IOUT} = \frac{0.8V}{R_{ISETH}} \times 2500A$$

exp) 
$$R_{ISETL} = 40k\Omega$$
  $I_{IOUT} = \frac{0.8V}{40k\Omega} \times 250 = 5mA$ 

exp) 
$$R_{ISETH} = 40k\Omega$$
  $I_{IOUT} = \frac{0.8V}{40k\Omega} \times 2500 = 50mA$ 

#### 3. Current Control at Output Saturation

When  $V_{\text{IOUT}}$  (=V<sub>F</sub>) -  $V_{\text{IN}}$  > 0.5V (TYP), the LED current I<sub>F</sub> is decreased to a set current 20 $\mu$ A (TYP). Therefore, V<sub>F</sub> decreases due to the decrease in the current. Open detection can be prevented by keeping  $V_{\text{IOUT}} \leq V_{\text{IN}}$ -0.5V. The current controlled to I<sub>OUT</sub><20 $\mu$ A and the LED current I<sub>F</sub> must be set so that V<sub>F</sub> does not exceed V<sub>UVLO\_OPEN</sub> by 20 $\mu$ A. If  $V_{\text{IN}} < V_{\text{UVLO_OPEN}}$  this function is not active.



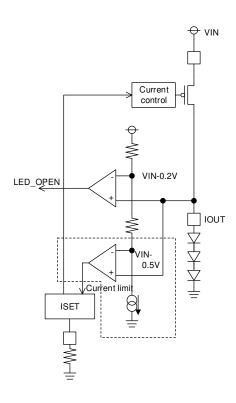


Figure 15. Current Control at Output Saturation

#### 4. PROTECT BUS (PBUS)

PBUS is an I/O terminal that outputs any detected error by switching PBUS from Hi-Z (Note 1) to Low. The output current can also be turned OFF by pulling the PBUS Low. When driving multiple LEDs through multiple ICs, as shown in the figure below, all the rows of LEDs can be turned OFF by any fault by connecting PBUS terminal to each IC. (Note1) PBUS terminal is an open drain terminal. Even when used separately, please be pulled up(10kΩ) to power supply voltage.

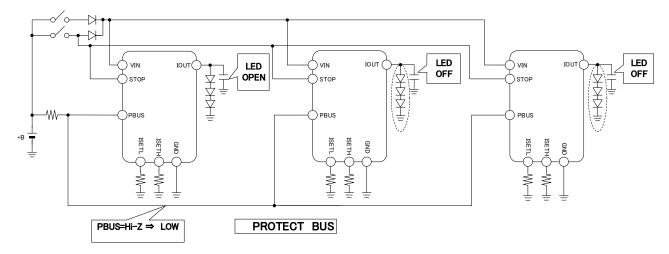


Figure 16. PBUS Function

●Example of operating protection for an LED open condition

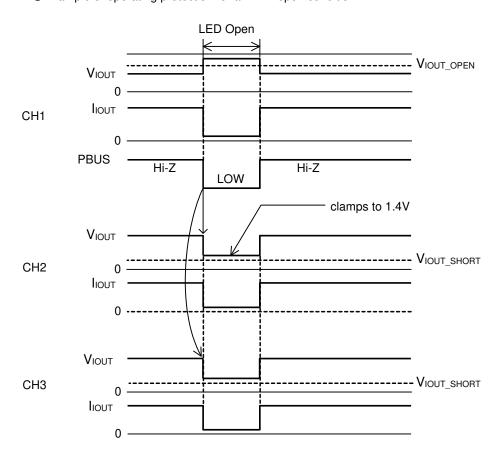


Figure 17. Example of protective Operation

When LED becomes open on the first IC, PBUS of IC1 is switched from Hi-Z to Low. As PBUS becomes Low, the other ICs detect the error and turns OFF their own LEDs. V<sub>IOUT</sub> clamps to 1.4V during the OFF period in order to prevent ground short protection.

#### 5. Protection Function

This IC has built-in short/open protection function for the external components. Any error detected will pull the PBUS terminal low.

(1) LED Open Detecting Function When any LED connected at the IOUT becomes open, V<sub>IOUT</sub> will go HIGH. When an error is detected at V<sub>IOUT</sub> < V<sub>IOUT</sub> OPEN the PBUS is pulled LOW.

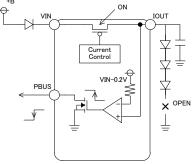


Figure 18. LED Open detection function

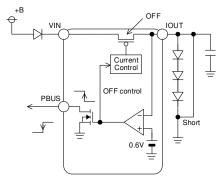


Figure 19. LED Short detection function

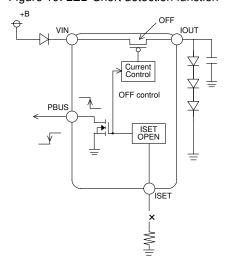


Figure 20. ISET Pin open detection function

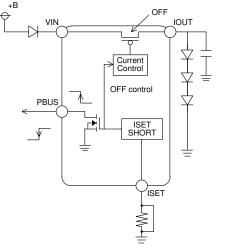


Figure 21. ISET Pin short detection function

## (2) LED Short Detecting Function

When the LEDs connected at the IOUT terminal are shorted to ground,  $V_{\text{IOUT}}$  will go LOW. When an error is detected at  $V_{\text{IOUT}} < V_{\text{IOUT\_SHORT}}$  0.6V (TYP) the output current is turned OFF to prevent IC heating and the PBUS is pulled LOW.

## (3) ISET(H/L) Open Detection Function

When the external resistance connected to ISET(H/L) terminal is open, ISET(H/L) open detection will be activated by decreasing the ISET(H/L) terminal current. At L mode, ISETL open detection is activated nevertheless state of the ISETH terminal. Also at H mode, ISETH open detection is activated nevertheless state of the ISETL terminal. The output current is turned off While detecting open and it can be notify the abnormally by changing the PBUS terminal output to low.

#### (4) ISET(H/L) Short Detection Function

When the external resistance connected to ISET(H/L) terminal is short to GND, ISET(H/L) short detection will be activated by increasing the ISET(H/L) terminal current. At L mode, ISETL short detection is activated nevertheless state of the ISETH terminal. Also at H mode, ISETH short detection is activated nevertheless state of the ISETL terminal. The output current is turned off While detecting short to GND and it can be notify the abnormally by changing the PBUS terminal output to low.

## 6. Over Voltage Protection

Overvoltage protection works in  $(R_{ISETH}=40k\Omega)$ , 18V  $(TYP) \le V_{IN}$  at  $I_{OUT}=200mA$  setting and limits output current to suppress the upswing in heat generation of LSI.

The overvoltage mute protection is effective only for (STOP=High) at H mode time.

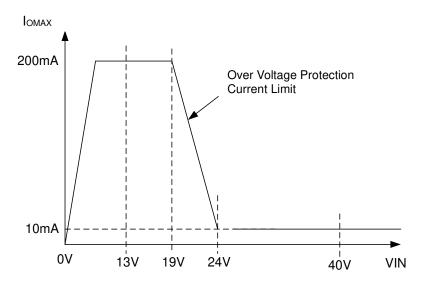


Figure 22. Overvoltage mute function

## **Recommended application circuit**

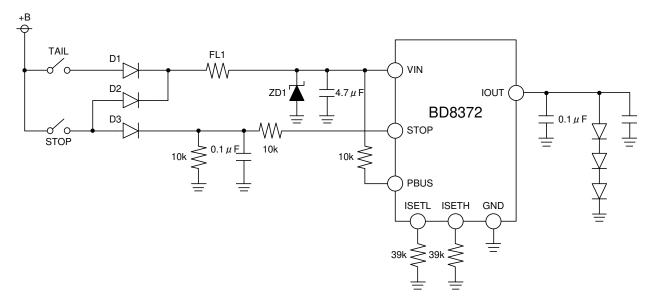


Figure 23. Recommended application circuit

(Note) EMC ISO 11452-2 (ALSE) ISO 11452-4 (BCI) ISO 7637-2

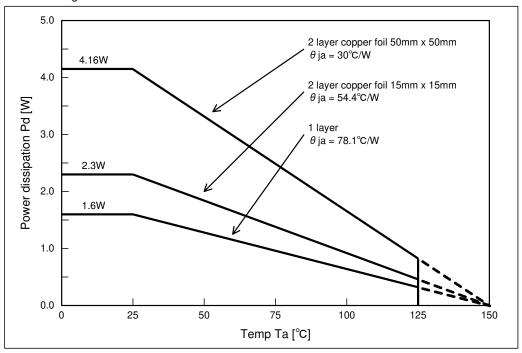
- pulse1
- Pulse2a,2b (level4)
- Pulse3a,3b (level4)

No.	Component Name	Component Value	Product Name	Company
1	D1	-	RF201L2S	ROHM
2	D2	-	RF201L2S	ROHM
3	D3	-	RF201L2S	ROHM
4	Z <sub>D1</sub>	-	TNR12H-220K	NIPPON CHEMICON
5	FL1	-	MMZ2012R102A	TDK
6	Cvin	4.7μF	GCM32ER71H475KA40	murata
7	Сюит	0.1μF	GCM188R11H104KA42	murata
8	CSTOP	0.1μF	GCM188R11H104KA42	murata
9	RISETL	39kΩ	MCR03 Series	ROHM
10	RISETH	39kΩ	MCR03 Series	ROHM
11	Rpbus	10kΩ	MCR03 Series	ROHM
12	R1	10kΩ	MCR03 Series	ROHM
13	R2	10kΩ	MCR03 Series	ROHM

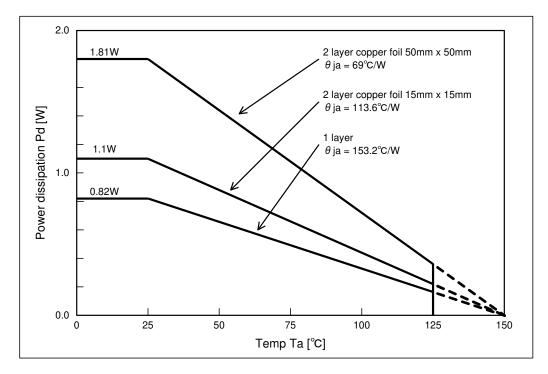
Table 1. BOM List

## **Power Dissipation**

## HRP7 Package



## HTSOP-J8 Package



(Caution1) When mounted with 70.0mm x 70.0mm x 1.6mm glass epoxy substrate.

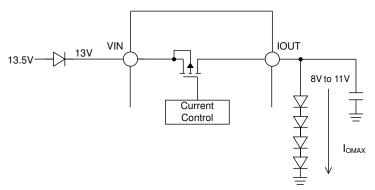
(Caution2) (Caution3) Abobe copper foil area indicates backside copper foil area.

Value changes according to number of substrate layers and copper foil area. Note that this value is a measured value. Not a guaranteed value.

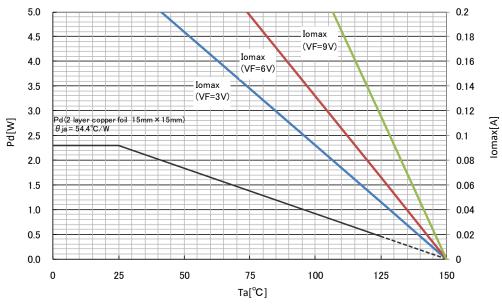
Figure 24. Thermal Dissipation Curve

## Pd (Power dissipation) and I<sub>OMAX</sub> (Permissible current)

The relation between Pd and I<sub>OMAX</sub> by V<sub>F</sub> of LED connected with IOUT is shown.



HRP7 Iomax-Ta、Pd-Ta characteristics (Pd=2.3W)



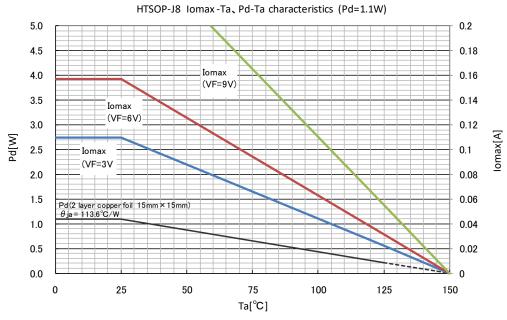
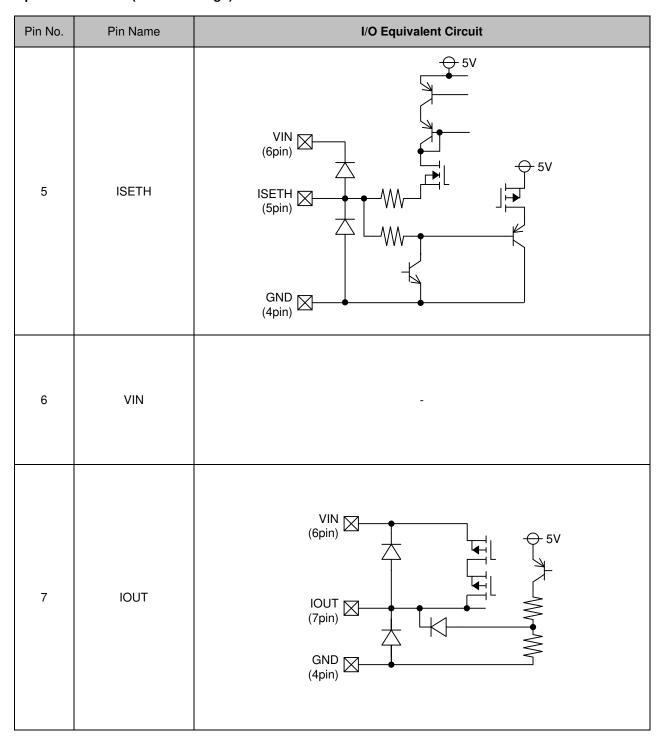


Figure 25. Heat reduction curve

## I/O Equivalent Circuit (HRP7 Package)

Pin No.	Pin Name	I/O Equivalent Circuit
1	STOP	VIN (6pin) 55V  STOP (1pin) 300kΩ  GND (4pin)
2	PBUS	VIN (6pin)  PBUS (2pin)  GND (4pin)
3	ISETL	VIN (6pin)  ISETL (3pin)  GND (4pin)
4	GND	-

## I/O Equivalent Circuit (HRP7 Package)- continued



## **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

## 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

## 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

## **Operational Notes - continued**

## 11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

#### 12. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

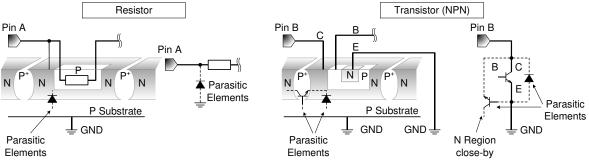


Figure 26. Example of monolithic IC structure

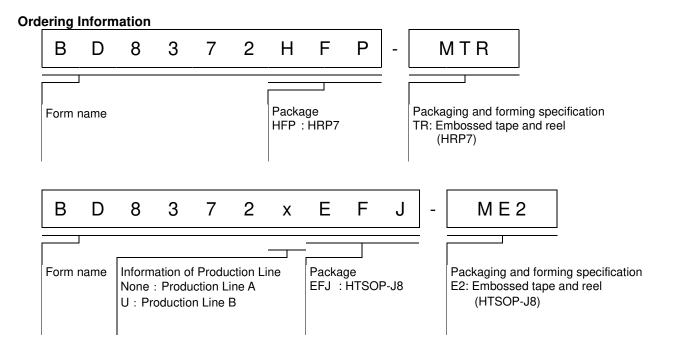
## 13. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

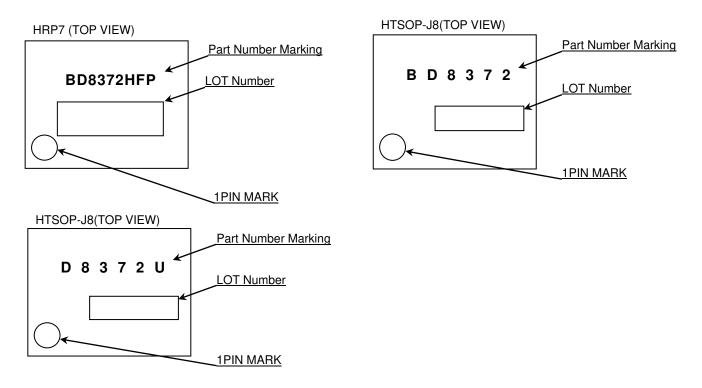
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

#### 14. Sudden Voltage Surge on VIN

Because MOSFETs are used in the output, a very steep change in the VCC voltage may cause the transistors to conduct large current. Take this condition into account when selecting the value of external circuit constants for a certain application.



## **Marking Diagrams**

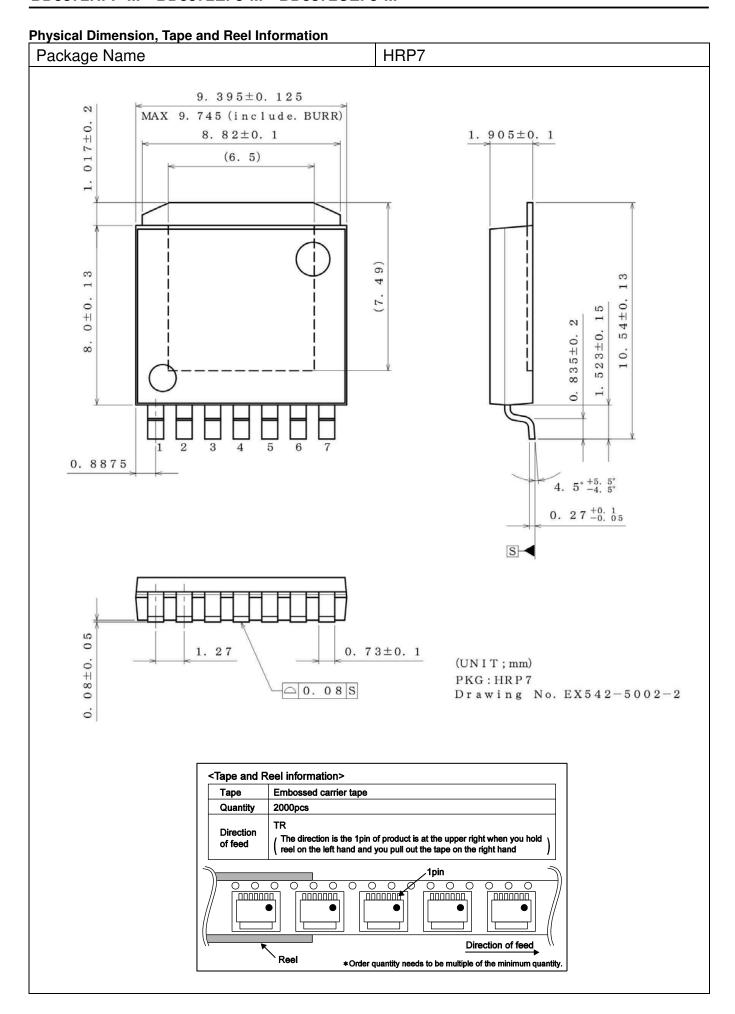


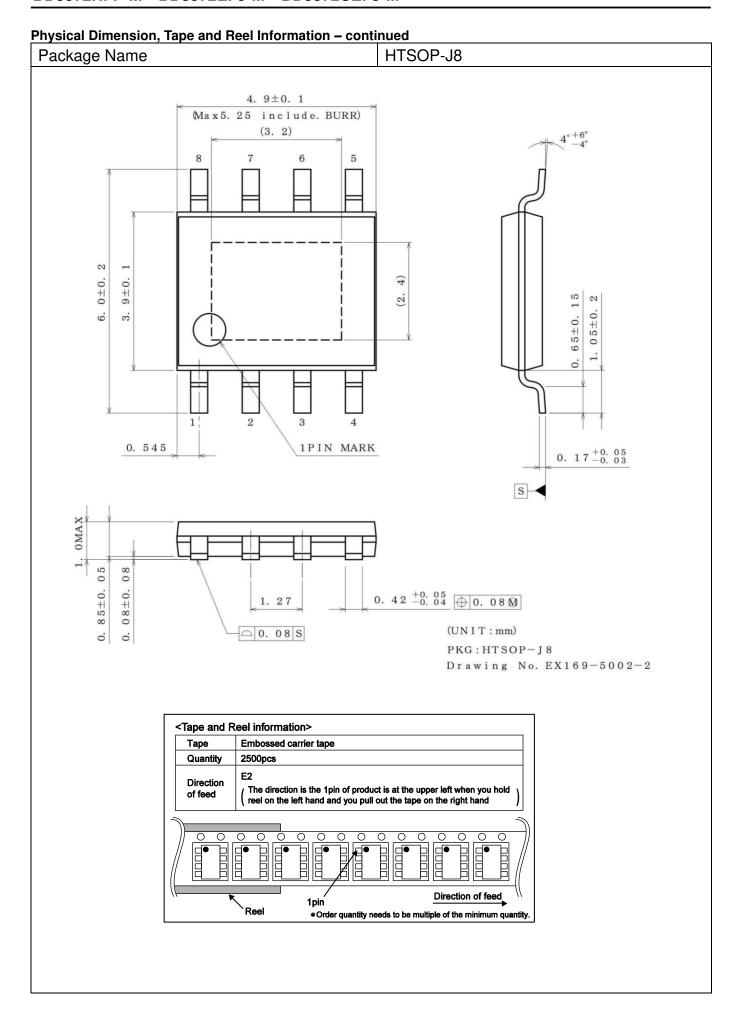
Part Number Marking	Package		Part Number	Note
BD8372HFP	HRP7	Reel of 2000	BD8372HFP-MTR	-
BD8372	HTSOP-J8	Dool of 2500	BD8372EFJ-ME2	Production Line A (Note 1)
D8372U	HISOF-JO	Reel of 2500	BD8372UEFJ-ME2	Production Line B (Note 1)

(Note 1) For the purpose of improving production efficiency, Production Line A and B have a multi-line configuration.

Electric characteristics noted in Datasheet does not differ between Production Line A and B.

Production Line B is recommended for new product.





## **Revision History**

Date	Revision	Changes
06.Nov.2015	001	New Release
09.Oct.2018	002	Page. 5 Circuit Current Symbol In $\Rightarrow$ Ivin STOP Input Current Symbol Vin_STOP $\Rightarrow$ Iin_STOP IN Over Voltage Current $\Rightarrow$ Over Voltage Mute Voltage Page. 8 Figure 13. Timming chart modify Page. 10 exp) $R_{ISETL} = 16k\Omega \Rightarrow \exp$ $R_{ISETL} = 40k\Omega$ Page. 11 Figure 15. Vuloo_OPEN $\Rightarrow$ Vuvlo_OPEN VDRH_IOUT  Page.13 Figure 18. 20. 21. modify 5. Protection Function PUBS $\Rightarrow$ PBUS (3)ISET(H/L) Open Detection Function change words (4)ISET(H/L) Short Detection Function change words  Page.15 Figure 23. $2.5k\Omega@100MHz$ delete comment Table 1. BOM List $5$ FL1 HMZ2012R102A $\Rightarrow$ MMZ2012R102A Page.18 I/O Equivalent Circuit add word (HRP7 Package) $2$ PBUS (28pin) $\Rightarrow$ (2pin)
01.Nov.2022	003	Page. 1 BD8372UEFJ-M Add Page. 22 BD8372UEFJ-M Add

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(Note1) Medical Equipment Classification of the Specific Applications

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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSIIb	CLASSⅢ
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
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  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

## **Precaution for Mounting / Circuit board design**

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

## **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

## **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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When disposing Products please dispose them properly using an authorized industry waste company.

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